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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/541,957	02/02/2006	Walter Fix	411000-138	8170
27162 7590 01/28/2008 CARELLA, BYRNE, BAIN, GILFILLAN, CECCHI, STEWART & OLSTEIN 5 BECKER FARM ROAD ROSELAND, NJ 07068			EXAMINER CHHAYA, SWAPNEEL	
			ART UNIT 2822	PAPER NUMBER
			MAIL DATE 01/28/2008	DELIVERY MODE PAPER

**Please find below and/or attached an Office communication concerning this application or proceeding.**

The time period for reply, if any, is set in the attached communication.

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<b>Office Action Summary</b>	<b>Application No.</b> 10/541,957	<b>Applicant(s)</b> FIX ET AL.	
	<b>Examiner</b> Swapneel Chhaya	<b>Art Unit</b> 2822	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

#### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

#### Status

- 1) ☒ Responsive to communication(s) filed on 08 July 2005.
- 2a) ☒ This action is **FINAL**.                      2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

#### Disposition of Claims

- 4) ☒ Claim(s) 1,2,4-10 and 12-20 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1,2,4-10 and 12-20 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

#### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 10/17/2007, 7/8/2005 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

#### Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All    b) ☐ Some \*    c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

#### Attachment(s)

- |  |   |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892)   | 4) <input type="checkbox"/> Interview Summary (PTO-413)<br>Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)                       | 5) <input type="checkbox"/> Notice of Informal Patent Application                       |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)<br>Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____  |

## DETAILED ACTION

### *Claim Rejections - 35 USC § 103*

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1, 2, 5, 6, 9, 10, 14, 17, 3, 11, 15, and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hart (U.S. Patent 6, 362, 509).

Regarding claim 1, An organic field effect transistor (10, 20, Fig. 1) including a gate (18, 28, Fig.1) comprising:

at least

a first electrode layer forming a source or a drain electrode (14, 15, Fig. 2a, column 5 lines 15-30, 47-55) each and having multiple sides

a semiconducting layer (5, Fig. 1, column 5 lines 15-30)

an insulator layer (6, Fig. 1, column 5 lines 15-30); and

one of the source and drain electrode in the first electrode layer surrounding the respective other electrode of the first electrode layer in a two-dimensional manner with

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the exception of one of said sides of the other electrode (14, 15, Fig. 2a, column 5 lines 15-30, 47-55)

a second electrode layer forming a gate electrode(18, 28), the semiconducting layer (5) exhibiting a current channel in the presence of an applied voltage and wherein the second electrode layer( completely overlies the current channel and overlies a portion of the source or drain electrodes of the first electrode layer, the overlying portion with respect to the source or drain electrodes having a width in the range from 0 to 20  $\mu\text{m}$  and having a length in the range of the length of the current channel; (Fig. 1 column 5 lines 10-40)

Hart discloses the claimed invention in claims 3 and 11 except for the additionally covered part having a width in the range from 0 to 20  $\mu\text{m}$  and having a length in the range of the length of the current channel.. It would have been obvious to one having ordinary skill in the art at the time the invention was made to use the range from 0 to 20  $\mu\text{m}$ , since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art. *In re Aller*, 105 USPQ 233.

whereby a u-shaped and/or meandering current channel (Fig. 2a), which begins and ends on one of said sides of the electrode of the first electrode layer, is formed in the

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semiconducting layer, please note that the examiner is referring to the area between the two electrodes.

Regarding claim 2, The OFET as claimed in claim 1 wherein, in the first electrodes layer respectively bounds the other electrode layer on three of four sides (Fig.2a)

Regarding claim 5 and 14, An integrated circuit having at least two OFETs (10, 20, 30) as claimed in claim 1 wherein the at least two OFETs are arranged into a NAND (51) or NOR gate such that the one sides of the two OFETs are respectively opposite one another.(Fig. 2 column 5 lines 46-60)

Regarding claim 6, 17, the integrated circuit as claimed in claim 5; including connecting lines (39) and/or inputs (19, 29) and outputs respectively situated in a region between the one sides.(Fig. 2 column 5 lines 50-65)

Regarding claim 9, the integrated circuit as claimed in claim 5 including a through-contact (42) in said first electrode layer (Fig. 2a column 5 lines 50-60)

Regarding claim 10 The integrated circuit as claimed in claim 9, wherein the through-

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contact (42) extends at least to one further side of the OFET other than said one side (Fig. 2a column 5 lines 50-60)

Regarding claim 15, Hart discloses an integrated circuit having at least two OFETs (10, 20, 30) as claimed in claim 3 wherein the at least two OFETs are arranged into a NAND (51) or NOR gate such that the one sides of the two OFETs are respectively opposite one another. (Fig. 2 column 5 lines 46-60)

Regarding claim 18, the integrated circuit as claimed in claim 15; including connecting lines (39) and/or inputs 19, 29) and outputs respectively situated in a region between the one sides.(Fig. 2a column 5 lines 50-65).

3. Claims 4, 7, 8, 12, 13, 16, and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hart as applied to claims 1 and 3 above in view of Ahn et Al. (U.S. Patent 6, 559, 920).

Regarding claims 4, 7, 8, 12 and 13, Hart discloses the claimed invention except for the holes and/or interruptions present in the semiconductor layer and/or between the one sides. Ahn teaches that it is known to have holes and/or interruptions are in the semiconductor layer (202, Fig. 5B, 5D column 5 lines 9-11). It would have been obvious

to one having ordinary skill in the art at the time the invention was made to incorporate holes and/or interruptions as taught by Ahn, since Ahn states at column 5 lines 10-11 that such a modification would decrease leakage current.

Regarding claim 16, Hart discloses an integrated circuit having at least two OFETs (10, 20, 30) as claimed in claim 4 wherein the at least two OFETs are arranged into a NAND (51) or NOR gate such that the one sides of the two OFETs are respectively opposite one another. (Fig. 2A column 5 lines 46-60)

Regarding claim 19, Hart discloses the integrated circuit as claimed in claim 5; including connecting lines (39) and/or inputs (19, 29) and outputs respectively situated in a region between the one sides. (Fig. 2a column 5 lines 50-65)

### ***Response to Arguments***

4. Applicant's arguments with respect to claims 1,2,4-10,12-20 have been considered but are moot in view of the new ground(s) of rejection.

### ***Conclusion***

5. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within

TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Swapneel Chhaya whose telephone number is 571-270-1434. The examiner can normally be reached on Monday- Thursday 7:30-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra Smith can be reached on 571-272-2429. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.



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SC

*Zandra V. Smith*  
Zandra V. Smith  
Supervisory Patent Examiner  
27 Jan 2008